Preferred Device

# **Sensitive Gate Silicon Controlled Rectifiers**

# **Reverse Blocking Thyristors**

Designed for industrial and consumer applications such as temperature, light and speed control; process and remote controls; warning systems; capacitive discharge circuits and MPU interface.

- Center Gate Geometry for Uniform Current Density
- All Diffused and Glass-Passivated Junctions for Parameter Uniformity and Stability
- Small, Rugged Thermowatt Construction for Low Thermal Resistance, High Heat Dissipation and Durability
- Low Trigger Currents, 200 μA Maximum for Direct Driving from Integrated Circuits
- Device Marking: Logo, Device Type, e.g., MCR72–3, Date Code

### **MAXIMUM RATINGS** (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage(1)  (T <sub>J</sub> = -40 to 110°C, Sine Wave, 50 to 60 Hz, Gate Open) MCR72–3  MCR72–6  MCR72–8	VDRM, VRRM	100 400 600	Volts
On-State RMS Current (180° Conduction Angles; T <sub>C</sub> = 83°C)	I <sub>T(RMS)</sub>	8.0	Amps
Peak Non-Repetitive Surge Current (1/2 Cycle, 60 Hz, T <sub>J</sub> = 110°C)	ITSM	100	Amps
Circuit Fusing Considerations (t = 8.3 ms)	I <sup>2</sup> t	40	A <sup>2</sup> s
Forward Peak Gate Voltage (t ≤ 10 μs, T <sub>C</sub> = 83°C)	V <sub>GM</sub>	±5.0	Volts
Forward Peak Gate Current (t $\leq$ 10 $\mu$ s, T <sub>C</sub> = 83°C)	I <sub>GM</sub>	1.0	Amp
Forward Peak Gate Power (t $\leq$ 10 $\mu$ s, T <sub>C</sub> = 83°C)	PGM	5.0	Watts
Average Gate Power (t = 8.3 ms, T <sub>C</sub> = 83°C)	PG(AV)	0.75	Watt
Operating Junction Temperature Range	TJ	-40 to +110	°C
Storage Temperature Range	T <sub>Stg</sub>	-40 to +150	°C
Mounting Torque	_	8.0	in. lb.

(1) V<sub>DRM</sub> and V<sub>RRM</sub> for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

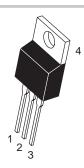


## ON Semiconductor

http://onsemi.com

# SCRs 8 AMPERES RMS 100 thru 600 VOLTS





TO-220AB CASE 221A STYLE 3

PIN ASSIGNMENT			
1	Cathode		
2	Anode		
3	Gate		
4	Anode		

#### ORDERING INFORMATION

Device	Package	Shipping
MCR72-3	TO220AB	500/Box
MCR72-6	TO220AB	500/Box
MCR72-8	TO220AB	500/Box

**Preferred** devices are recommended choices for future use and best overall value.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	2.2	°C/W
Thermal Resistance, Junction to Ambient		60	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	TL	260	°C

### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted.)

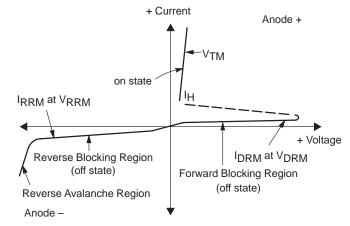
Symbol	Min	Тур	Max	Unit
•			•	•
I <sub>DRM</sub> , I <sub>RRM</sub>	_	_	10 500	μA μA
VTM	_	1.7	2.0	Volts
lGT	_	30	200	μА
VGT	_	0.5	1.5	Volts
V <sub>GD</sub>	0.1	_	_	Volts
lн	_	_	6.0	mA
tgt	_	1.0	_	μs
dv/dt	_	10		V/µs
	VTM  GT  VGD  IH  tgt	IDRM, IRRM	IDRM, IRRM	IDRM, IRRM

<sup>(1)</sup> Ratings apply for negative gate voltage or R<sub>GK</sub> = 1 kΩ. Devices shall not have a positive gate voltage concurrently with a negative voltage on the anode. Devices should not be tested with a constant current source for forward and reverse blocking capability such that the voltage applied exceeds the rated blocking voltage.

<sup>(2)</sup> RGK current not included in measurement.

## **Voltage Current Characteristic of SCR**

Symbol	Parameter
V <sub>DRM</sub>	Peak Repetitive Off State Forward Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Off State Reverse Voltage
IRRM	Peak Reverse Blocking Current
V <sub>TM</sub>	Peak On State Voltage
I⊔	Holding Current



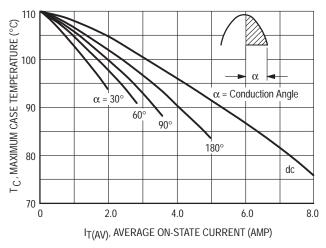
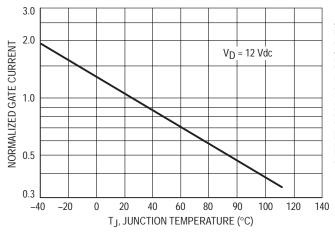


Figure 1. Average Current Derating

Figure 2. On-State Power Dissipation



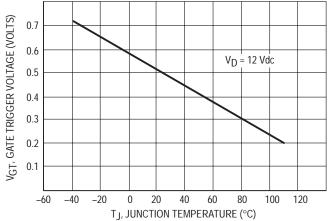
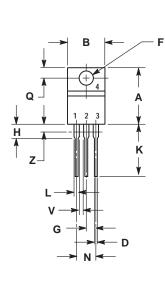


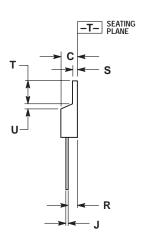
Figure 3. Normalized Gate Current

Figure 4. Gate Voltage

#### PACKAGE DIMENSIONS

## TO-220AB CASE 221A-07 **ISSUE Z**





#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
   DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.014	0.022	0.36	0.55
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

STYLE 3:

PIN 1. CATHODE

ANODE 2.

GATE ANODE

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